

## **IXFT24N80P Datasheet**



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DiGi Electronics Part Number IXFT24N80P-DG

Manufacturer IXYS

Manufacturer Product Number IXFT24N80P

Description MOSFET N-CH 800V 24A TO268

Detailed Description N-Channel 800 V 24A (Tc) 650W (Tc) Surface Mount

TO-268AA



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXFT24N80P	IXYS
Series:	Product Status:
HiPerFET™, Polar	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
800 V	24A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	400mOhm @ 12A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5V @ 4mA	105 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	7200 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	650W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
TO-268AA	TO-268-3, D³Pak (2 Leads + Tab), TO-268AA
Base Product Number:	
IXFT24	

## **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



## **OUR CERTIFICATE**

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